TFT DISPLAY SPECIFICATION

RAYSTAR

RAYSTAR Optronics, Inc. 曜凌光電股份有限公司



曜凌光電股份有限公司 Raystar Optronics, Inc.

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RFM1040F-AIW-LNN

SPECIFICATION

CUSTOMER:

APPROVED BY

PCB VERSION

DATE

FOR CUSTOMER USE ONLY

SALES BY	APPROVED BY	CHECKED BY	PREPARED BY

Release DATE:

TFT Display Inspection Specification: <u>https://www.raystar-optronics.com/download/products.htm</u> Precaution in use of TFT module: <u>https://www.raystar-optronics.com/download/declaration.htm</u>



Revision History

VERSION	DATE	REVISED PAGE NO.	Note
0	2017/10/25		First issue
K			



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1.Module Classification Information

R	F	Μ	104	0F	-	Α	I	W	-	L	Ν	Ν
1	2	3	4	5	-	6	7	8	-	9	10	11

Item	Description								
1	R : Raystar Optronics Inc.								
2	Display Type : $F \rightarrow TFT$ Type, $J \rightarrow Custom TFT$								
3	K:1280	480 G:640x480 H:1024x600 I:320x480 J:240x320							
4	Display Size:1	0.4" TFT							
5	Version Code.								
6	J:TFT+FR+A/I N:TFT+FR+A/ BOARD	D BOARD+CONTROL DWER BOARD (DC TO DC)							
7	Polarizer Type, Temperature range, View direction	ROLBOARDI→Transmissive, W. T, 6:00 ;C→Transmissive, N. T, 6:00L→Transmissive, W.T,12:00 ;F→Transmissive, N.T,12:00Y→Transmissive, W.T, IPS TFT ;A→Transmissive, N.T, IPS TFTZ→Transmissive, W.T, O-TFTR→Transmissive, Super W.T, O-TFT							
8	Backlight	N→Transmissive, Super W.T, 6:00;Q→Transmissive, Super W.T, 12:00V→Transmissive, Super W.T, VA TFTW : LED, WhiteF : CCFL, White							
9	Driver Method	D: Digital A: Analog L : LVDS M:MIPI							
10	Interface	N : without control board A : 8Bit B : 16Bit S:SPI Interface R: RS232 U:USB I: I2C							
11	TS	S:SPI InterfaceR: RS2320:0SB1:12CN : Without TSS : resistive touch panelC : capacitive touch panel capacitive touch panel (G-F-F)G : capacitive touch panel(G-G)							





2.Summary

The RF104F is a color active matrix thin film transistor (TFT) liquid crystal display (LCD) that uses amorphous silicon TFT as a switching device. It is composed of a TFT LCD panel, a timing controller, voltage reference, common voltage, column driver, and row driver circuit. This TFT LCD has a 10.4-inch diagonally measured active display area with XGA resolution (1,024 horizontal by 768 vertical pixels array).



3.General Specifications

- Size: 10.4 inch
- Dot Matrix: 1024 x R.G.B. x 768 dots
- Module dimension: 236.0*176.9*5.7 mm
- Active area: 211.2 *158.4 mm
- Dot pitch: 0.20625 x 0.20625 mm
- LCD type: TFT, Normally White, Transmissive
- Gray scale inversion direction: 6 o'clock
- Backlight Type: LED ,Normally White
- Interface: LVDS
- With /Without TP: Without TP
- Surface: Anti-Glare

*Color tone slight changed by temperature and driving voltage.



4.1. Signal Connector Type

Item	Description
Type/Part Number	MSB24013P20HA (Manufacture by STM)
Mating Receptacle / Type (Reference)	P24013P20 or compatible

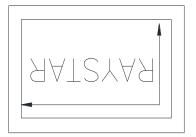
Signal Connector Pin Assignment

Pin No.	Symbol	Description	Note
1	VDD	Power Supply, 3.3V (typical)	-
2	VDD	Power Supply, 3.3V (typical)	-
3	VSS	Ground	-
4	REV	Reverse Scan selection {High:2.5(min), 3.3(typ),3.6(max); Low: 0.5(max)}	(1)
5	Rin1-	-LVDS differential data input (R0-R5,G0)	-
6	Rin1+	+LVDS differential data input (R0-R5,G0)	-
7	VSS	Ground	-
8	Rin2-	-LVDS differential data input (G1-G5,B0-B1)	-
9	Rin2+	+LVDS differential data input (G1-G5,B0-B1)	-
10	VSS	Ground	-
11	Rin3-	-LVDS differential data input (B2-B5,HS,VS,DE)	-
12	Rin3+	+LVDS differential data input (B2-B5,HS,VS,DE)	-
13	VSS	Ground	-
14	ClkIN-	-LVDS differential clock input	-
15	ClkIN+	+LVDS differential clock input	-
16	GND	Ground	-
17	Rin4-	-LVDS differential data input (R6-R7,G6-G7,B6-B7)	-
18	Rin4+	+VDS differential data input (R6-R7,G6-G7,B6-B7)	-
19	SEL68	6/8 bits LVDS data input selection(H:8bits L/NC:6bits)	-
20	Bist	Internal use	-

Note (1) REV = LOW/NC

(2) REV = High







4.2. LVDS Receiver

Signal Electrical Characteristics For LVDS Receiver The built-in LVDS receiver is compatible with (ANSI/TIA/TIA-644) standard.

 Table 8 LVDS Receiver Electrical Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Differential Input High Threshold	Vth	-	-	+100	mV	VCM =+1.2V
Differential Input Low Threshold	Vtl	-100	-	-	mV	VCM =+1.2V
Magnitude Differential Input	VID	200	-	600	mV	
Common Mode Voltage	VCM	1.0	1.2	1.4	V	Vth – Vtl=200 mV
Common Mode Voltage Offset	ΔVCM	-50	-	+50	mV	Vth – Vtl=200 mV

Note:(1) Input signals shall be low or Hi- resistance state when VDD is off.

(2) All electrical characteristics for LVDS signal are defined and shall be measured at the interface connector of LCD

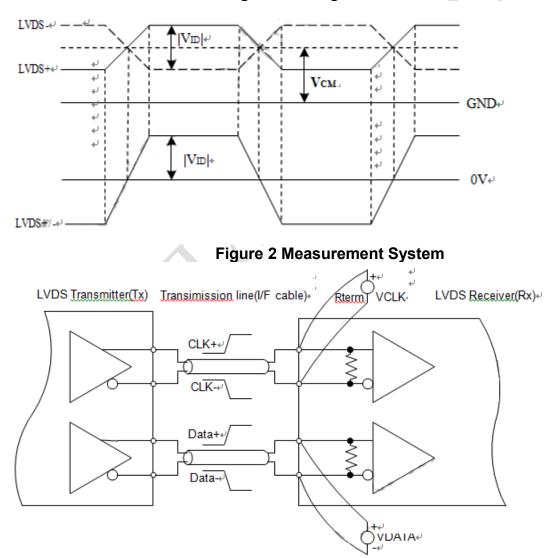
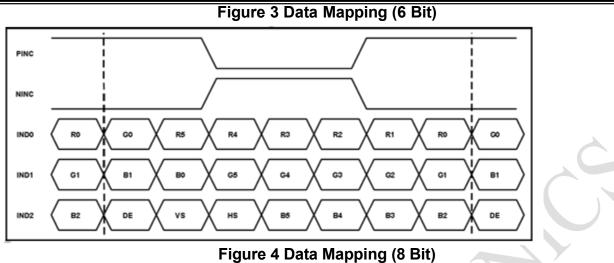
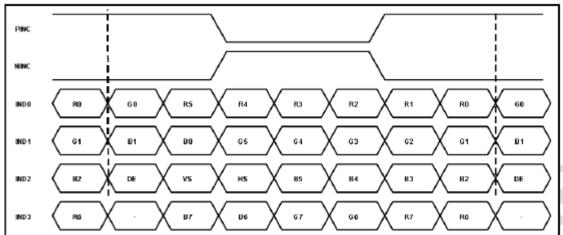


Figure 1 Voltage Definitions



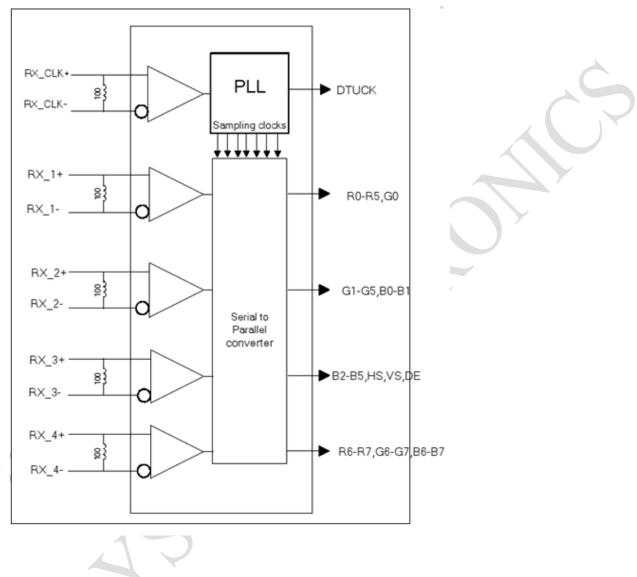






LVDS Receiver Internal Circuit

Figure 4 LVDS Receiver Internal Circuit shows the internal block diagram of the LVDS receiver. This LCD module equips termination resistors for LVDS link.





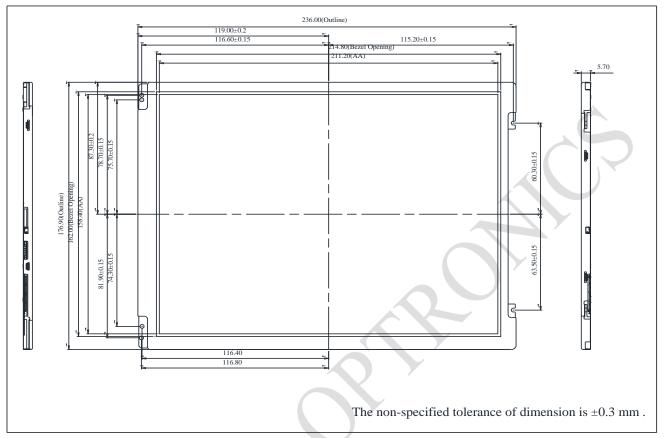
4.3. Backlight Connector Type

Item	Description				
Туре	MSB24038P5A (Manufacture by STM)				
Mating Receptacle / Type (Reference)	P24038P5				
Backlight Connector Pin Assignment					

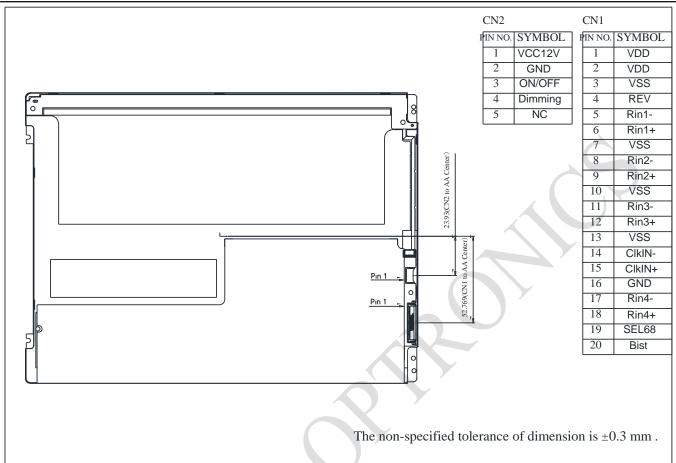
Pin No. Symbol Signal name VCC 12V 1 GND 2 GND ON/OFF 5V-ON,0V-OFF 3 4 Dimming PWM Dimming or Analog Dimming 5 NC NC



5.Contour Drawing







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6.Block Diagram LVDS Connector 1 Gate Driver IC TFT Array/Cell DC 1024X768 Pixels Power DC/DC Converter Ŧ Source/TCON IC Gamma Correction Generation Connector: Circuit LED Light Bar LED LED Boost Current Power Balance Circuit



7.Absolute Maximum Ratings

Item	Symbol	Min	Тур	Max	Unit
Operating Temperature	TOP	-20		+70	
Storage Temperature	TST	-30	_	+80	

Note: Device is subject to be damaged permanently if stresses beyond those absolute maximum ratings listed above

1. Temp. □60□, 90% RH MAX. Temp. >60□, Absolute humidity shall be less than 90% RH at 60□



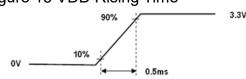
8.Electrical Characteristics

8.1. Input power specifications are as follows.

Table 1 Power Consumption

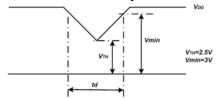
ltem		Symbol	Min.	Тур.	Max.	Units	Note
LCD Drive Voltage (Logic)		VDD	3.0	3.3	3.6	V	(2), (4)
VDD Current	Black Pattern	IDD	-	TBD	(0.25)	А	(3),(4)
VDD Power Consumption	Black Pattern	PDD	-	-	(0.84)	W	(3),(4)
Rush Current		Irush	-	-	1.5	A	(1),(4)
Allowable Logic/LCD Drive Ripple Voltage		VDDrp	-	-	(200)	mV	(4)

Note (1) Measure Condition Figure 15 VDD Rising Time



Note (2) VDD Power Dip Condition

If VTH < VDD \leq Vmin $\,^{,}$ then td \leq 10ms ; when the voltage return to normal our panel must revive automatically



Note (3) Frame Rate=60Hz, VDD=3.3V, DC Current.

Note (4) Operating temperature 25°C, humidity 55%RH.

Power ON/OFF Sequence

VDD power on/off sequence is as follows. Interface signals are also shown in the chart. Signals from any system shall be Hi- resistance state or low level when VDD is off. Figure 17 Power Sequence

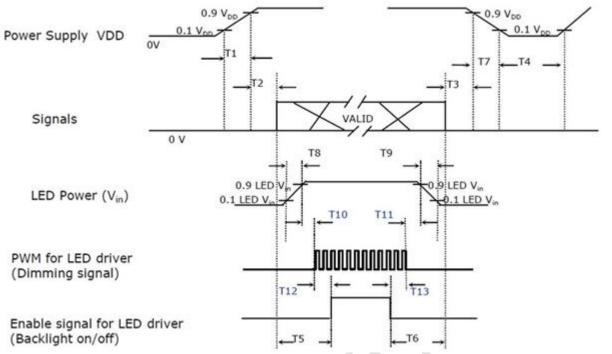


Table 2 Power Sequencing Requirements

Power ON/OFF Sequence									
Items	Symbol	MIN	TYP	MAX	Unit				
VDD rising time from 10% to 90%	T1	0.5	-	10	ms				
Delay from VDD to valid data at power ON	T2	30	-	50	ms				
Delay from valid data OFF to VDD OFF at power OFF	Т3	0	-	50	ms				
VDD OFF time for windows restart	T4	500	-	-	ms				
Delay from valid data to B/L enable at power ON	T5	200	-	-	ms				
Delay from valid data off to B/L disable at power Off	Т6	200	-	-	ms				
VDD falling time from 90% to 10%	T7	0.5	-	10	ms				
LED Vin rising time from 10% to 90%	Т8	0.5	-	10	ms				
LED Vin falling time from 90% to 10%	Т9	0.5	-	10	ms				
Delay from LED driver Vin rising time 90% to PWM ON	T10	0	-	-	ms				
Delay from PWM Off to LED driver Vin falling time 10%,Must keep rule	T11	0	-	-	ms				
Delay from PWM ON to B/L Enable ON, Must keep rule	T12	0	-	-	ms				
Delay from B/L Enable Off to PWM Off	T13	0	-	-	ms				



8.2. Parameter Guideline Of LED Backlight

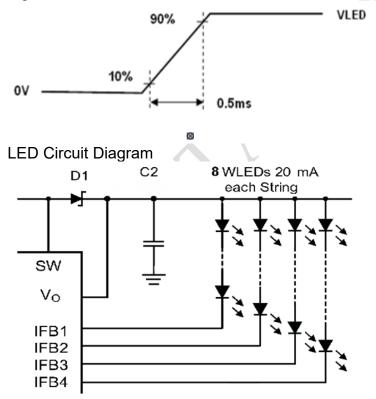
Table 3 Parameter Guideline for LED Backlight

Item	Symbol		Min.	Тур.	Max.	Units	Note
LED Input Voltage	V_LED	1	10.8	12	12.6	V	(2),(3)
LED Power Consumption	P_LED	1	-	-	(2.88)	W	(2),(3)
LED Forward Voltage	VF	2.8	3.2	3.6	V		
LED Forward Current	IF		-	20	30	mA	
DW/M Signal Valtage	VPW M_EN	High	4.5	5	5.5		
PWM Signal Voltage		Low	0	I	0.4	V	(2)
LED Enable Voltage	VLED EN	High	2.0	5	5.5		
LED Enable voltage	VLED_EN	Low	0	-	0.4	V	
Input PWM Frequency	FPWM		100	-	1K	Hz	
LED Life Time	LT		30,000	-	-	Hours	(1)(2)
Duty Ratio	PWM		5	-	100	%	(2)

Note (1) The LED life time define as the estimated time to 50% degradation of initial luminous. Note (2) Operating temperature 25° C, humidity 55%RH.

Note (3) A higher LED power supply voltage will result in better power efficiency. Keep the V_LED between 12V and 12.6V is strongly recommended.

Figure 8 LED Rush Current Measure Condition





9.Pixel Format Image

Figure 1 shows the relationship of the input signals and LCD pixel format image.

Figure 1 Pixel Format 3 2 1023 1024 1 4 RGBRGBRGBRGB. RGBRGB 1 2 RGB RGB RGB RGB ... RGBRGB 3 RGBRGBRGBRGB. RGBRGB : RGBRGB 767 RGBRGBRGBRGB. 768 RCBRCBRCB. RGBRGB



10.Interface Timings 10.1. Timing Characteristics

Synchronization method should be DE mode.

Table 1 Interface Timings

Parameter	Symbol	Unit	Min.	Тур.	Max.
LVDS Clock Frequency	Fclk	MHz	(52)	(65)	(71)
H Total Time	HT	Clocks	(1,114)	(1,344)	(1,400)
H Active Time	HA	Clocks	1,024	1,024	1,024
H Blanking Time	HBL	Clocks	(90)	(320)	(376)
V Total Time	VT	Lines	(778)	(806)	(845)
V Active Time	VA	Lines	768	768	768
V Blanking Time	VBL	Lines	(10)	(38)	(77)
Frame Rate	Vsync	Hz	55	60	65

Note: H Blanking Time and V Blanking Time can not be changed at every frame.



11.Optical Characteristics

ltem		Symbol	Condition.	Min	Тур.	Max.	Unit	Remark
Response tim	е	Tr Tf	θ=0° 、Φ=0°	-	16	-	.ms	Note 3,5
Contrast ratio		CR	At optimized viewing angle	720	900	-	-	Note 4,5
Color	White	Wx	θ=0° 、Φ=0	0.26	0.31	0.36		Note 2.6.7
Chromaticity	vvnite	Wy	$0 = 0 \forall \Phi = 0$	0.28	0.33	0.38		Note 2,6,7
	Hor.	ΘR		70	75	-		
Viewing		ΘL	CR≧10	70	75	-	Dea	Note 1
angle	Ver.	ΦT	CR≦ 10	70	75	-	Deg.	Note 1
	ver.	ΦВ		70	75	-		1
Brightness		-	-	300	350	-	cd/m ²	Center of display

Ta=25±2℃,

Note 1: Definition of viewing angle range

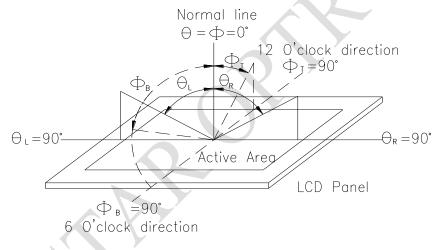


Fig.11.1. Definition of viewing angle

Note 2: Test equipment setup:

After stabilizing and leaving the panel alone at a driven temperature for 10 minutes, the measurement should be executed. Measurement should be executed in a stable, windless, and dark room. Optical specifications are measured by Topcon BM-7orBM-5 luminance meter 1.0° field of view at a distance of 50cm and normal direction.



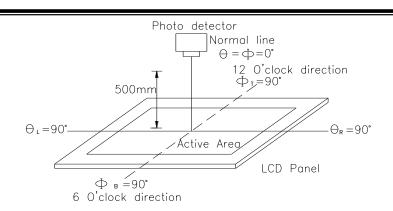
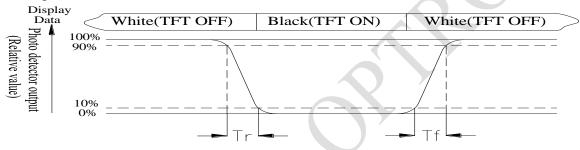


Fig. 11.2. Optical measurement system setup

Note 3: Definition of Response time:

The response time is defined as the LCD optical switching time interval between "White" state and "Black" state. Rise time, Tr, is the time between photo detector output intensity changed from 90% to 10%. And fall time, Tf, is the time between photo detector output intensity changed from 10% to 90%



Note 4: Definition of contrast ratio:

The contrast ratio is defined as the following expression.

Contrast ratio (CR) = $\frac{\text{Luminance measured when LCD on the "White" state}}{\frac{1}{2}$

Luminance measured when LCD on the "Black" state

Note 5: White Vi = Vi50 \pm 1.5V

Black Vi = Vi50 \pm 2.0V

"±" means that the analog input signal swings in phase with VCOM signal.

"±" means that the analog input signal swings out of phase with VCOM signal.

The 100% transmission is defined as the transmission of LCD panel when all the input terminals of module are electrically opened.

Note 6: Definition of color chromaticity (CIE 1931) Color coordinates measured at the center point of LCD

Note 7: Measured at the center area of the panel when all the input terminals of LCD panel are electrically opened.



12.Reliability

Content of Reliability Test (Wide temperature, -20 ~70)

Environmental Test

Test Item	Content of Test	Test Condition	Note
High Temperature	Endurance test applying the high storage temperature		2
storage	for a long time.	200hrs	
Low Temperature	Endurance test applying the low storage temperature	-30 🗆	1,2
storage	for a long time.	200hrs	
High Temperature	Endurance test applying the electric stress (Voltage &	70 🗆	
Operation	Current) and the thermal stress to the element for a long time.	200hrs	
Low Temperature	Endurance test applying the electric stress under low	-20□	1
Operation	temperature for a long time.	200hrs	
High Temperature/	The module should be allowed to stand at	60□,90%RH	1,2
Humidity Operation	60□,90%RH max	96hrs	
Thermal shock	The sample should be allowed stand the following 10	-20□/70□	
resistance	cycles of	10 cycles	
	operation		
	-20 25 70		
		1	
	30min 5min 30min 1 cycle		
Vibration test	Endurance test applying the vibration during	Total fixed	3
	transportation and using.	amplitude : 1.5mm	
		Vibration Frequency :	
		10~55Hz	
		One cycle 60 seconds to 3	
		directions of X,Y,Z for Each 15 minutes	
Otatia ale striaity to at	Endurance to stand on the standard strate to the	-	
Static electricity test	Endurance test applying the electric stress to the terminal.	VS=±600V(contact)	
	lemma.	,±800v(air),	
		RS=330Ω	
		CS=150pF	
		10 times	

Note1: No dew condensation to be observed.

Note2: The function test shall be conducted after 4 hours storage at the normal Temperature and humidity after remove from the test chamber.

Note3: The packing have to including into the vibration testing.



Page: 1

	LCM Sample	e Estimate Feedback Sheet
Module Number :		
1 · Panel Specification :		
1. Panel Type :	Pass	□ NG ,
2. View Direction :	Pass	□ NG ,
3. Numbers of Dots :	Pass	□ NG ,
4. View Area :	Pass	□ NG ,
5. Active Area :	Pass	□ NG ,
6.Operating Temperature :	Pass	□ NG ,
7.Storage Temperature :	Pass	□ NG ,
8.Others :		
2 · Mechanical Specification :		
1. PCB Size :	Pass	🗆 NG ,
2.Frame Size :	Pass	□ NG ,
3.Materal of Frame :	□ Pass	□ NG ,
4.Connector Position :	Pass	□ NG ,
5.Fix Hole Position :	Pass	□ NG ,
6.Backlight Position :	Pass	□ NG ,
7. Thickness of PCB :	Pass	□ NG ,
8. Height of Frame to PCB :	Pass	□ NG ,
9.Height of Module :	Pass	□ NG ,
10.Others:	Pass	□ NG ,
3 · <u>Relative Hole Size</u> :		
1.Pitch of Connector :	Pass	□ NG ,
2.Hole size of Connector :	Pass	□ NG ,
3.Mounting Hole size :	□ Pass	□ NG ,
4.Mounting Hole Type :	□ Pass	□ NG ,
5.Others :	□ Pass	□ NG ,
4 · Backlight Specification :		
1.B/L Type:	Pass	□ NG ,
2.B/L Color :	Pass	□ NG ,
3.B/L Driving Voltage (Referen	ice for LED Ty	/pe): □ Pass □ NG ,
4.B/L Driving Current :	Pass	□ NG ,
5.Brightness of B/L :	Pass	□ NG ,
6.B/L Solder Method :	Pass	□ NG ,
7.Others :	Pass	□ NG ,

>> Go to page 2 <<



Page: 2

Module Number :		
5 · Electronic Characteristics	of Module :	
1.Input Voltage :	□ Pass	□ NG ,
2.Supply Current :	Pass	□ NG ,
3.Driving Voltage for LCD :	□ Pass	□ NG ,
4.Contrast for LCD :	□ Pass	□ NG ,
5.B/L Driving Method :	□ Pass	□ NG ,
6.Negative Voltage Output :	□ Pass	□ NG ,
7.Interface Function :	□ Pass	□ NG ,
8.LCD Uniformity :	□ Pass	□ NG ,
9.ESD test :	□ Pass	□ NG ,
10.Others :	□ Pass	□ NG ,
6 ∖ Summary :	•	

Summary

Sales signature :	
Customer Signature :	

|--|